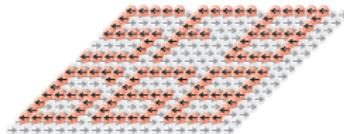




Universität Hamburg
DER FORSCHUNG | DER LEHRE | DER BILDUNG

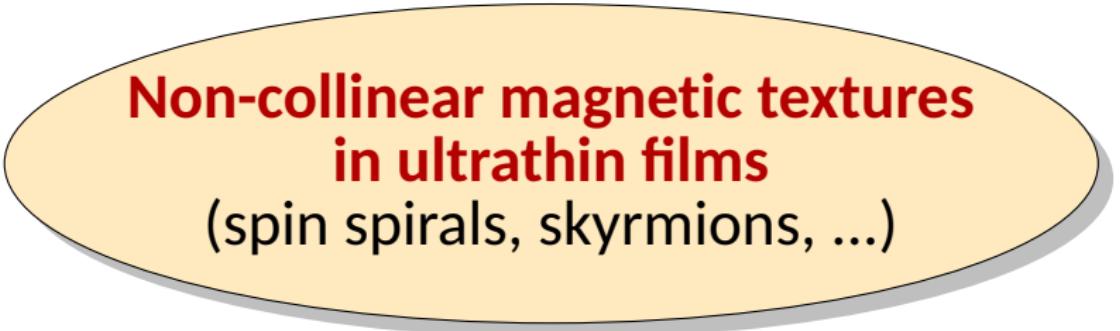


Funded by the Horizon2020
Framework Programme of
the European Union

Various ways to tune non-collinear magnetism in ultrathin films

*Aurore Finco, Pin-Jui Hsu, Levente Rózsa, Niklas Romming,
Elena Vedmedenko, André Kubetzka, Kirsten von Bergmann and
Roland Wiesendanger*

University of Hamburg



**Non-collinear magnetic textures
in ultrathin films**
(spin spirals, skyrmions, ...)

Competition between:

- ▶ Dipolar interactions
- ▶ Exchange interactions
- ▶ Dzyaloshinskii-Moriya interaction
- ▶ Magnetic anisotropy
- ▶ Higher order interactions



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Length
scale

Non-collinear magnetic textures in ultrathin films

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Chirality

Thermal
stability

Topology

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Hydrogenation

Temperature

Length scale

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Film thickness

Magnetic field

Choice of the interface



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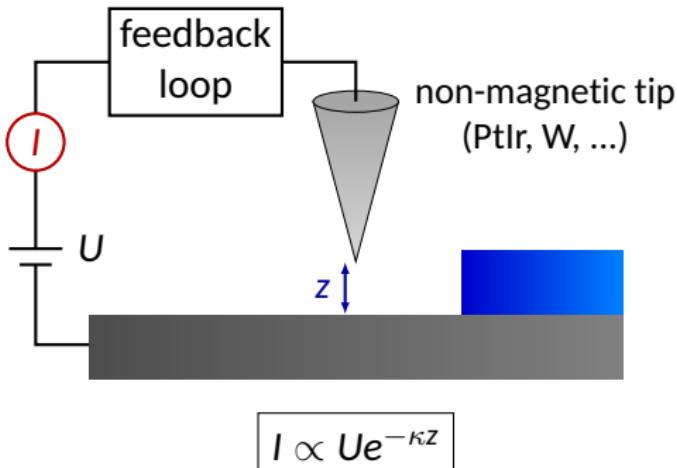
Choice of the
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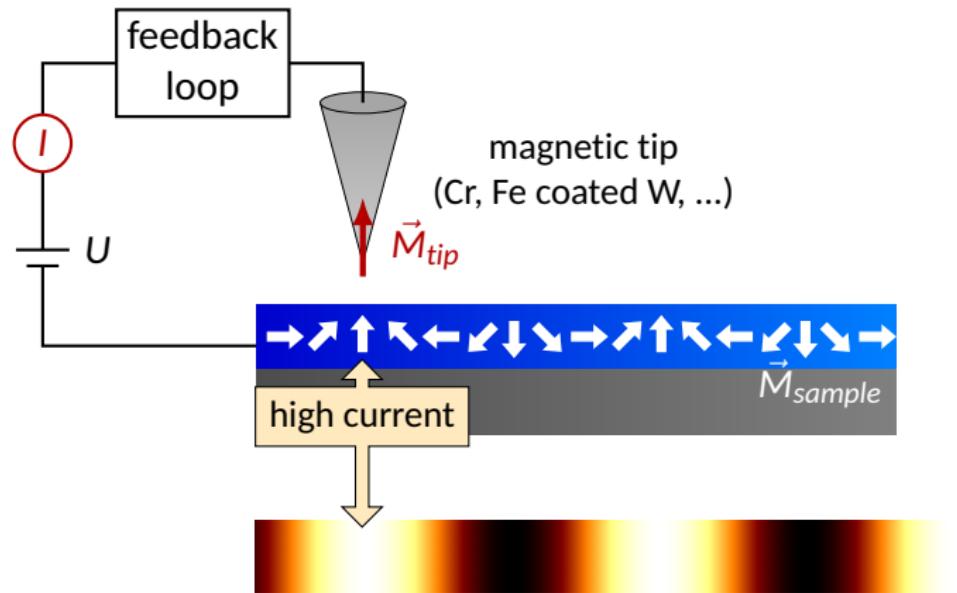
Scanning tunneling microscopy



- ▶ Feedback loop to keep the current constant and measure the topography of the surface
- ▶ Measurement of the differential conductance $\frac{dI}{dU}$ using lock-in technique
- ▶ $\frac{dI}{dU}$ gives access to the local density of states

Spin-polarized STM

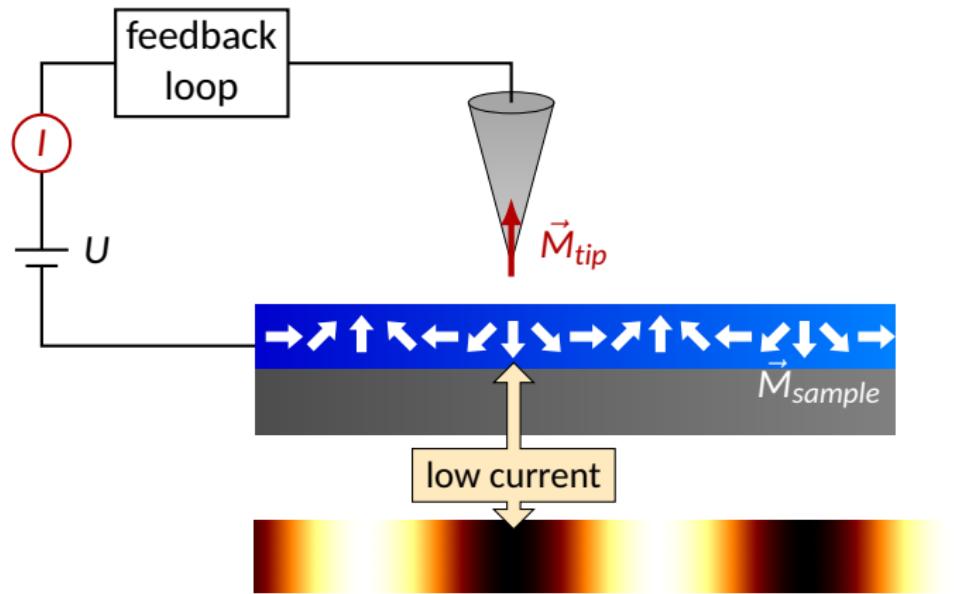
Tunneling MagnetoResistance



$$I = I_0 \left(1 + P_{sample} P_{tip} \cos(\vec{M}_{sample}, \vec{M}_{tip}) \right)$$

Spin-polarized STM

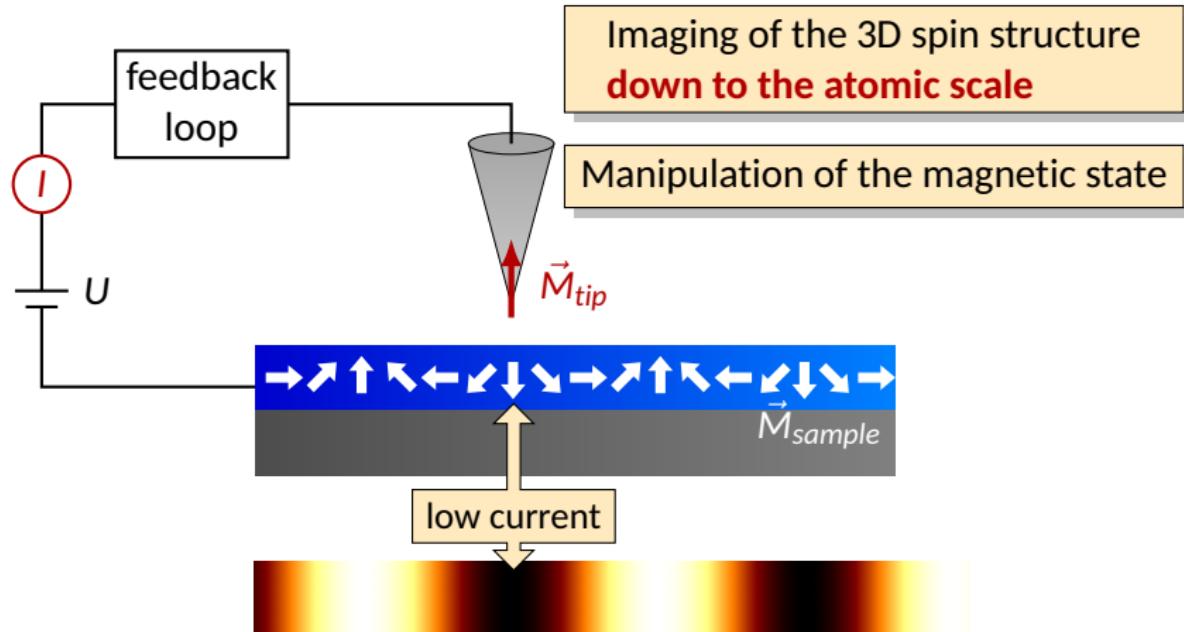
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Spin-polarized STM

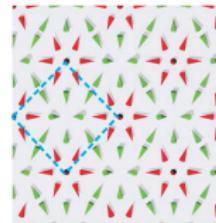
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The Fe/Ir interface

- ▶ Strong DMI, about 1.8 meV per atom.
 - Nanoskyrmion lattice in the monolayer Fe.

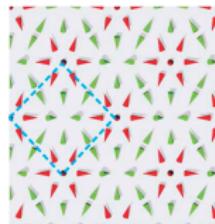


S. Heinze *et al.* Spontaneous atomic-scale magnetic skyrmion lattice in two dimensions. *Nature Physics* 7.9 (2011), 713–718.

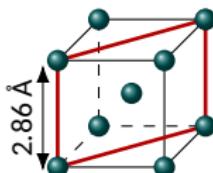
P.-J. Hsu *et al.* Guiding Spin Spirals by Local Uniaxial Strain Relief. *Physical Review Letters* 116 (2016), 017201.

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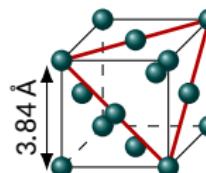


Bulk Fe: bcc



bcc(110) nearest neighbour
distance: $a = 2.47 \text{ \AA}$

Bulk Ir: fcc



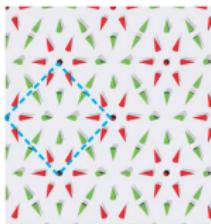
fcc(111) nearest neighbour
distance: $a = 2.72 \text{ \AA}$

S. Heinze *et al.* Spontaneous atomic-scale magnetic skyrmion lattice in two dimensions. *Nature Physics* 7.9 (2011), 713–718.

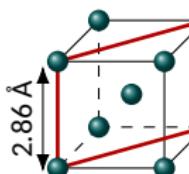
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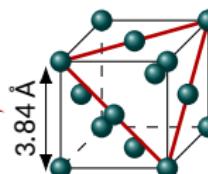


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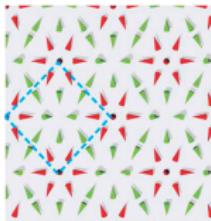
- Large strain on the Fe film.

S. Heinze *et al.* Spontaneous atomic-scale magnetic skyrmion lattice in two dimensions. *Nature Physics* 7.9 (2011), 713–718.

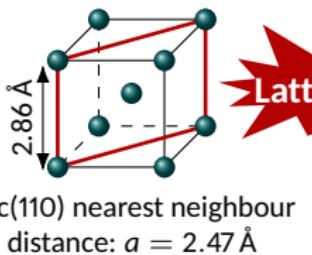
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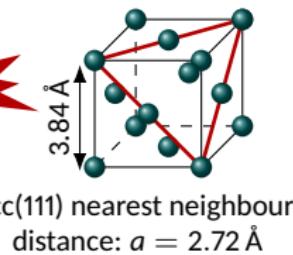
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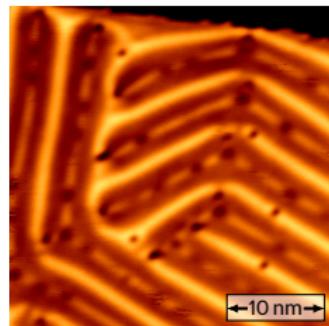


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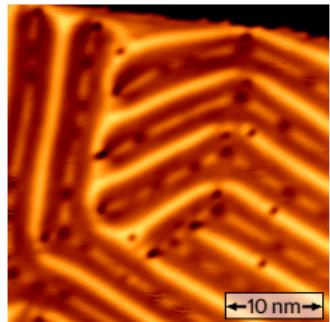
- Formation of dislocation lines when the thickness of the Fe film is larger than one atomic layer.



S. Heinze *et al.* Spontaneous atomic-scale magnetic skyrmion lattice in two dimensions. *Nature Physics* 7.9 (2011), 713–718.

P.-J. Hsu *et al.* Guiding Spin Spirals by Local Uniaxial Strain Relief. *Physical Review Letters* 116 (2016), 017201.

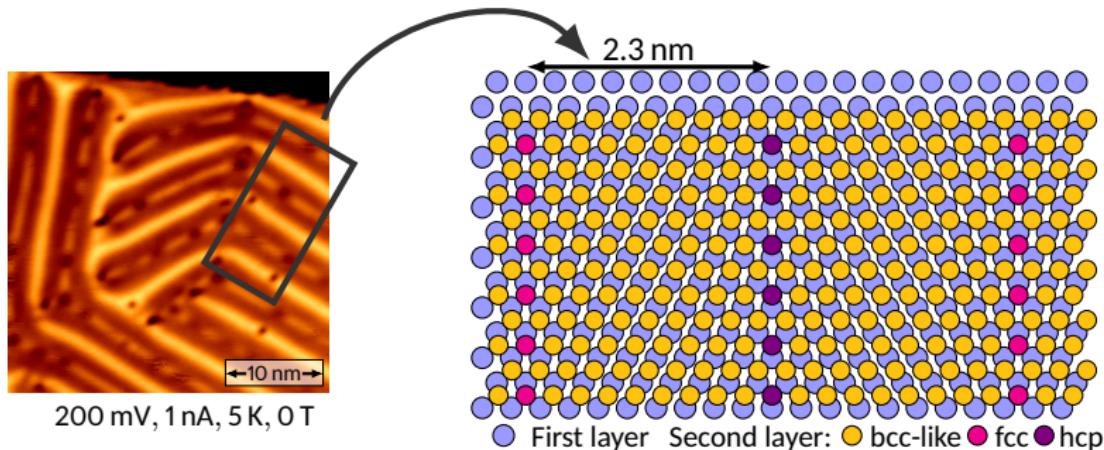
The double layer Fe on Ir(111)



200 mV, 1 nA, 5 K, 0 T

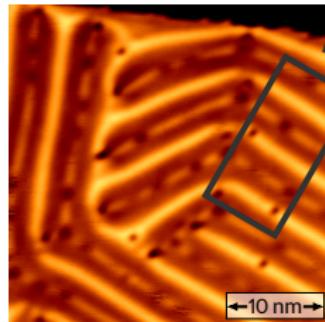
- ▶ Reconstruction lines along the 3 equivalent crystallographic directions
- ▶ Lines due to uniaxial strain release

The double layer Fe on Ir(111)

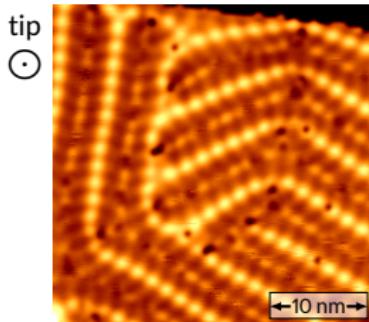
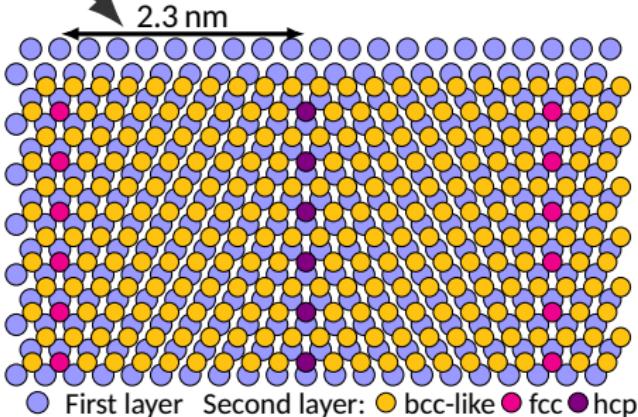


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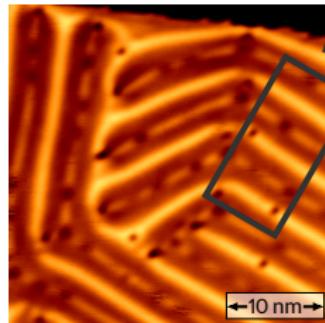
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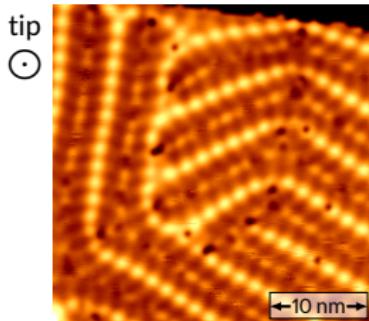
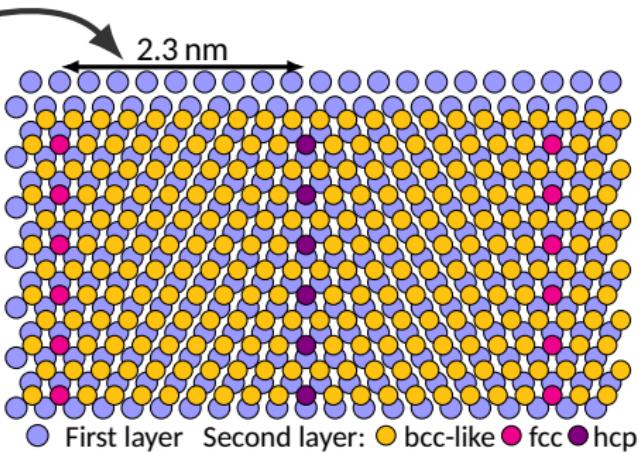
200 mV, 1 nA, 5 K, 4 T

- ▶ Reconstruction lines along the 3 equivalent crystallographic directions
- ▶ Lines due to uniaxial strain release

The double layer Fe on Ir(111)



200 mV, 1 nA, 5 K, 0 T

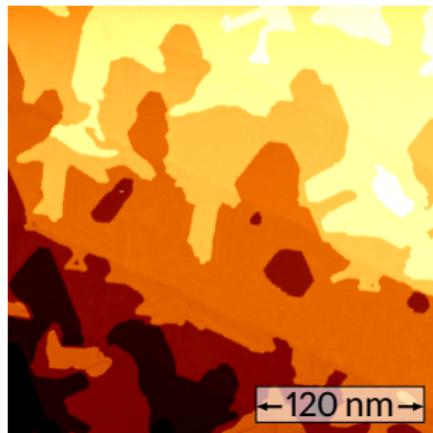


200 mV, 1 nA, 5 K, 4 T

- ▶ Reconstruction lines along the 3 equivalent crystallographic directions
- ▶ Lines due to uniaxial strain release
- ▶ Spin spirals propagate along the lines
- ▶ No change in out-of-plane magnetic field up to 9 T

Incorporate H in the Fe double layer

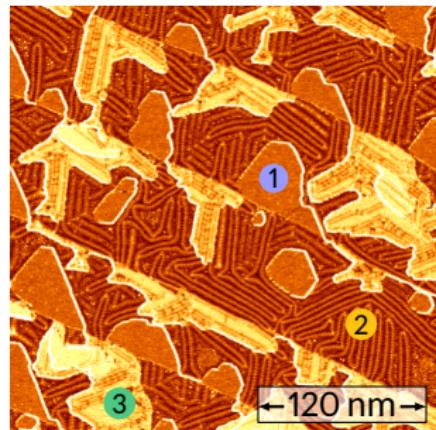
Constant current map



1V, 1nA, 4 K, Cr bulk tip

Incorporate H in the Fe double layer

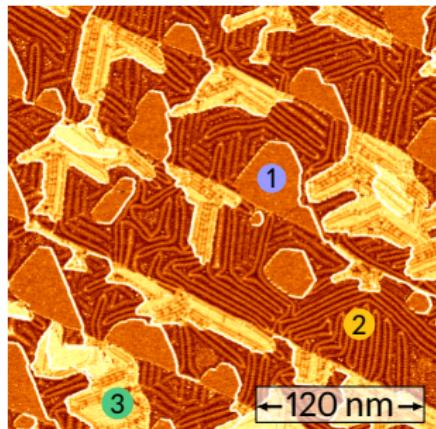
Differential conductance



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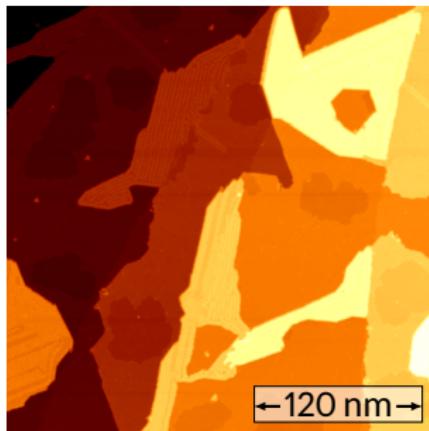
Differential conductance



- ▶ H dosing at room temperature
- ▶ Post-annealing at 300 °C



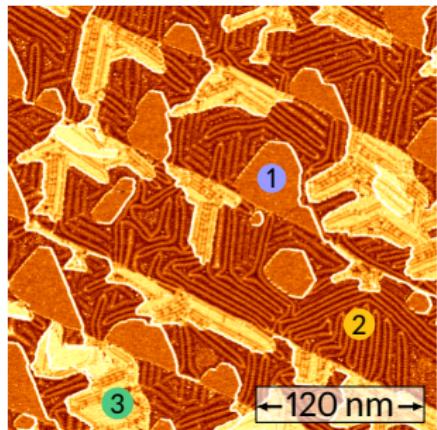
Constant current map



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Incorporate H in the Fe double layer

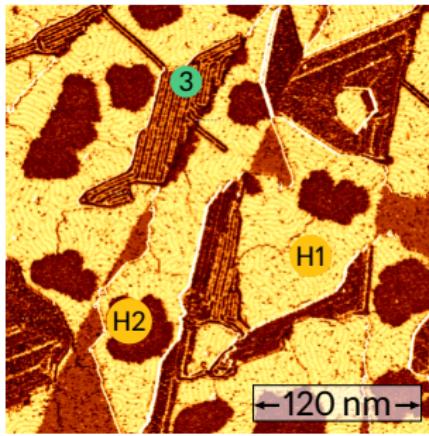
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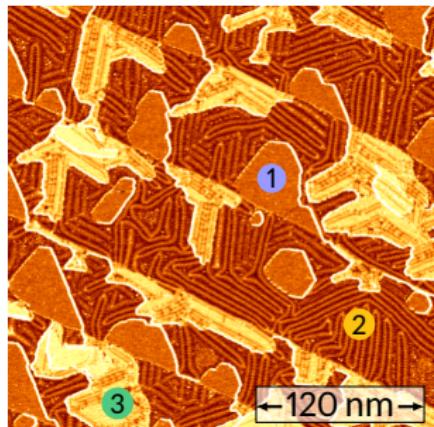


Differential conductance



Incorporate H in the Fe double layer

Differential conductance



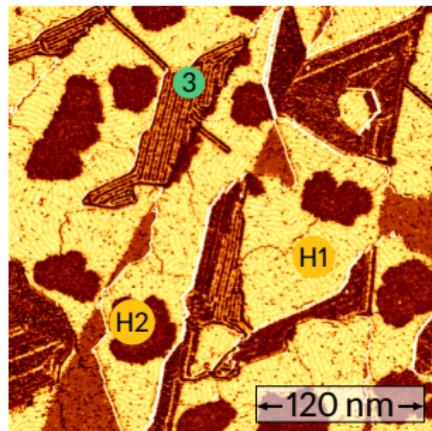
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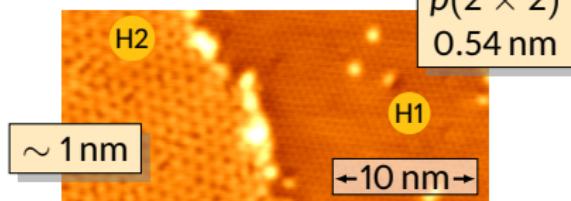


Differential conductance



1V, 1nA, 4 K, Cr bulk tip

Constant current map

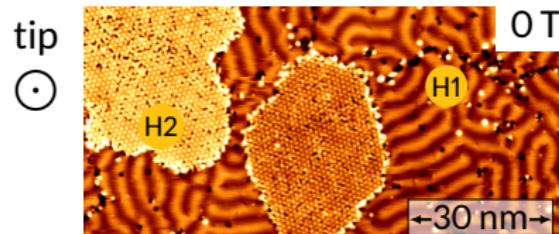


$\sim 1 \text{ nm}$

-200 mV, 1nA, 4K, Cr bulk tip

Magnetism of the hydrogenated phases

Constant current maps

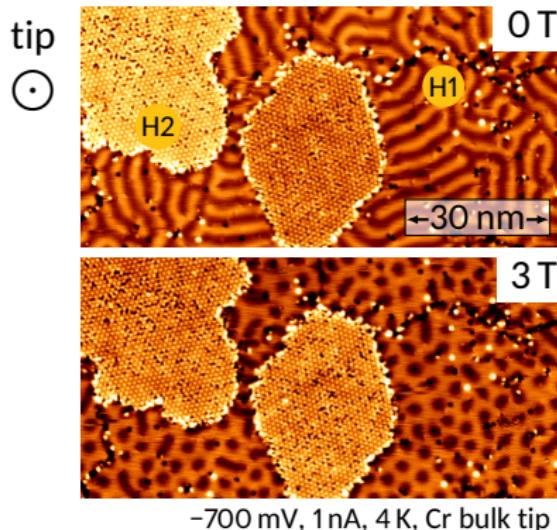


-700 mV, 1 nA, 4 K, Cr bulk tip

- ▶ H1: spin spirals, period 3.5 nm
- ▶ H2: ferromagnetic

Magnetism of the hydrogenated phases

Constant current maps

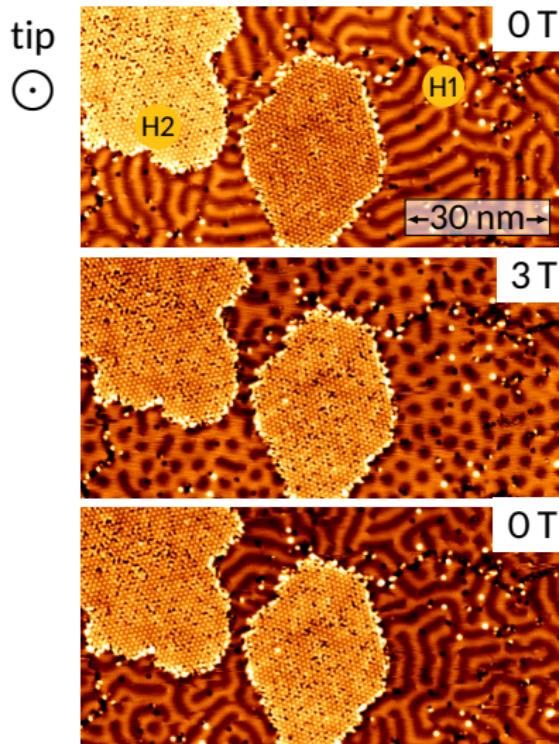


- ▶ H1: spin spirals, period 3.5 nm
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- ▶ H1: creation of skyrmions
- ▶ H2: switching

Magnetism of the hydrogenated phases

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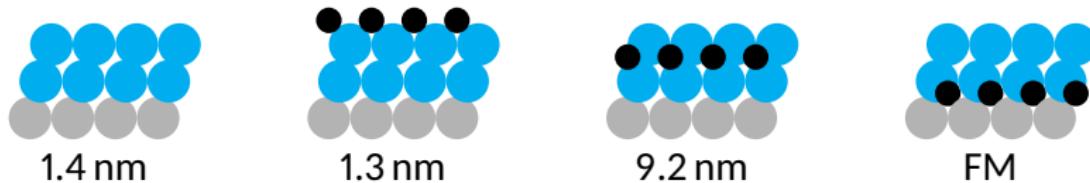
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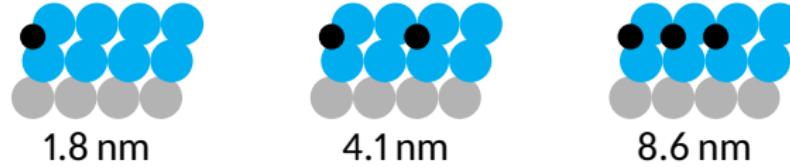
ab initio calculations

done by Levente Rózsa in collaboration with Krisztián Palotás, László Udvardi and László Szunyogh from Budapest

Position of the H atoms

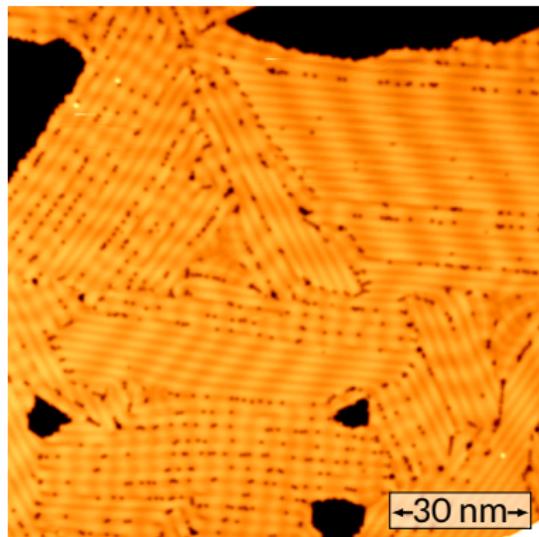


H concentration



The triple layer Fe on Ir(111)

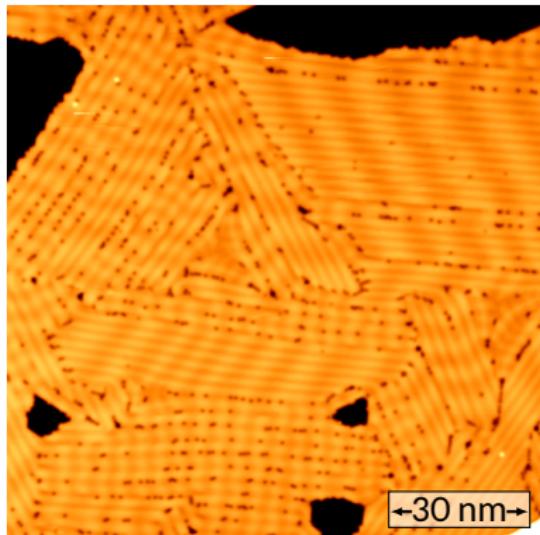
Constant current map



-700 mV, 1 nA, 8 K, 0 T, Cr bulk tip

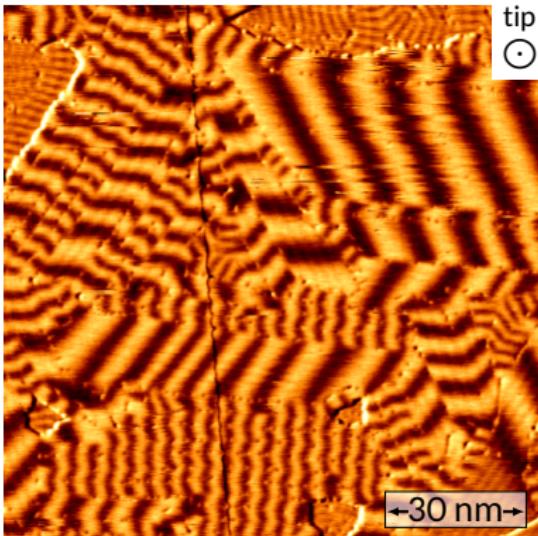
The triple layer Fe on Ir(111)

Constant current map



-700 mV, 1 nA, 8 K, 0 T, Cr bulk tip

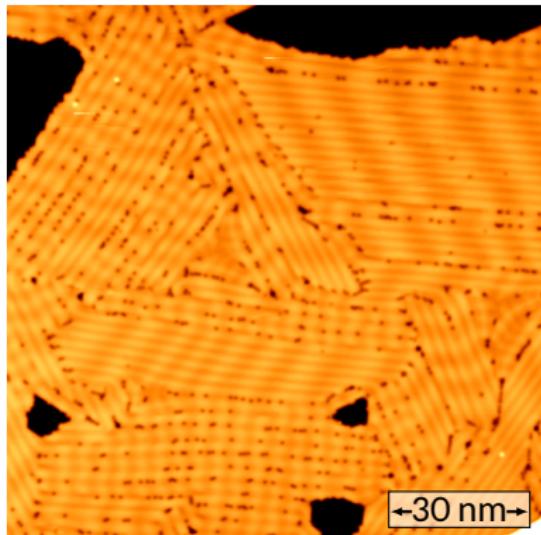
Differential conductance map



- ▶ Why do all the spirals look so different?
- ▶ What about the temperature stability?

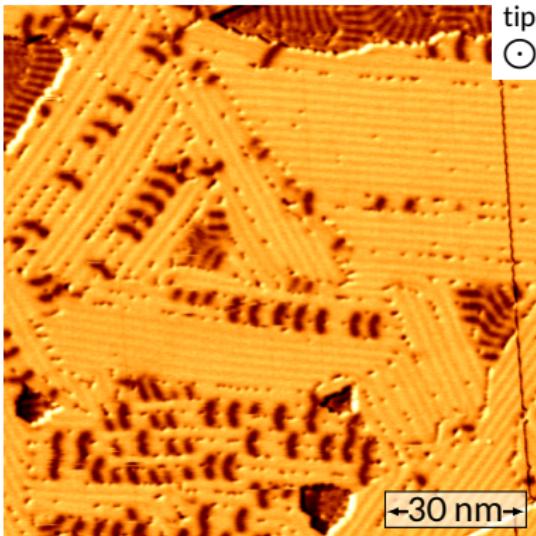
The triple layer Fe on Ir(111)

Constant current map



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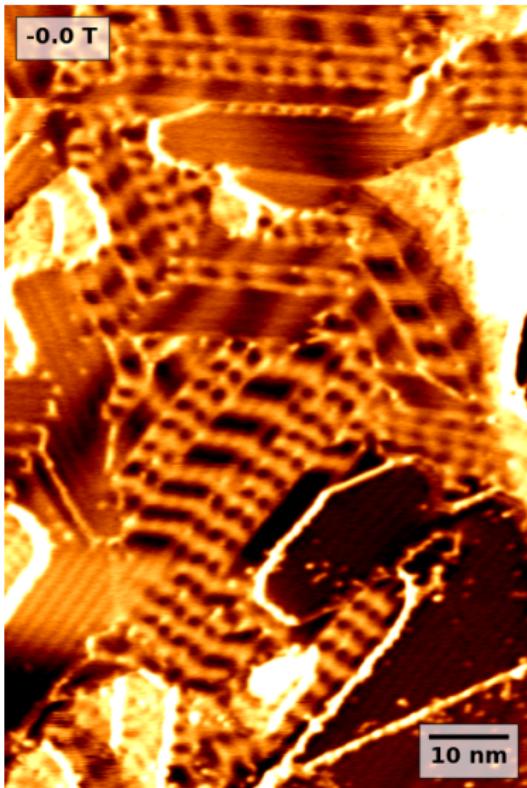
Differential conductance map



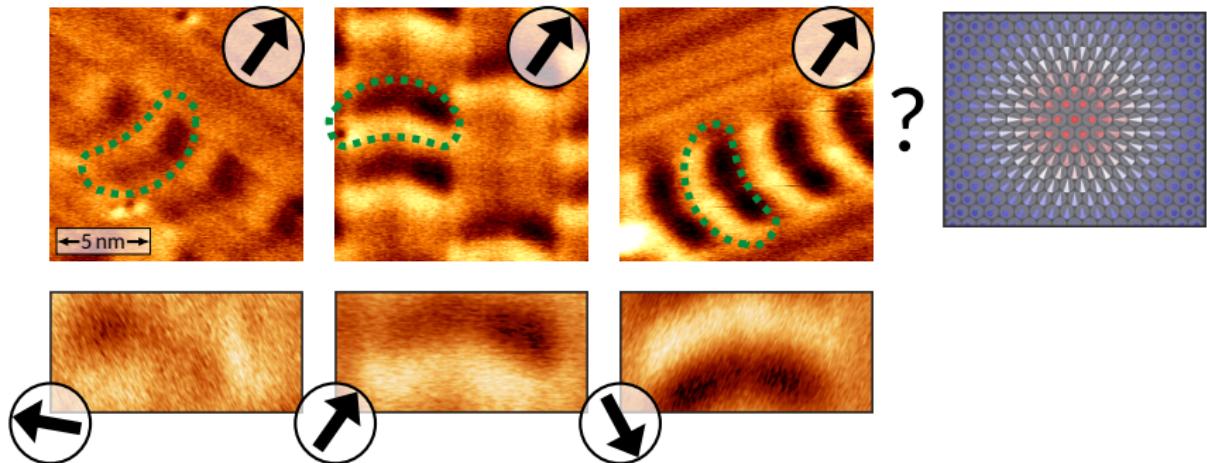
2.5 T

- ▶ Why do all the spirals look so different?
- ▶ What about the temperature stability?
- ▶ How does the magnetic field affect the state? Can we manipulate the created objects?

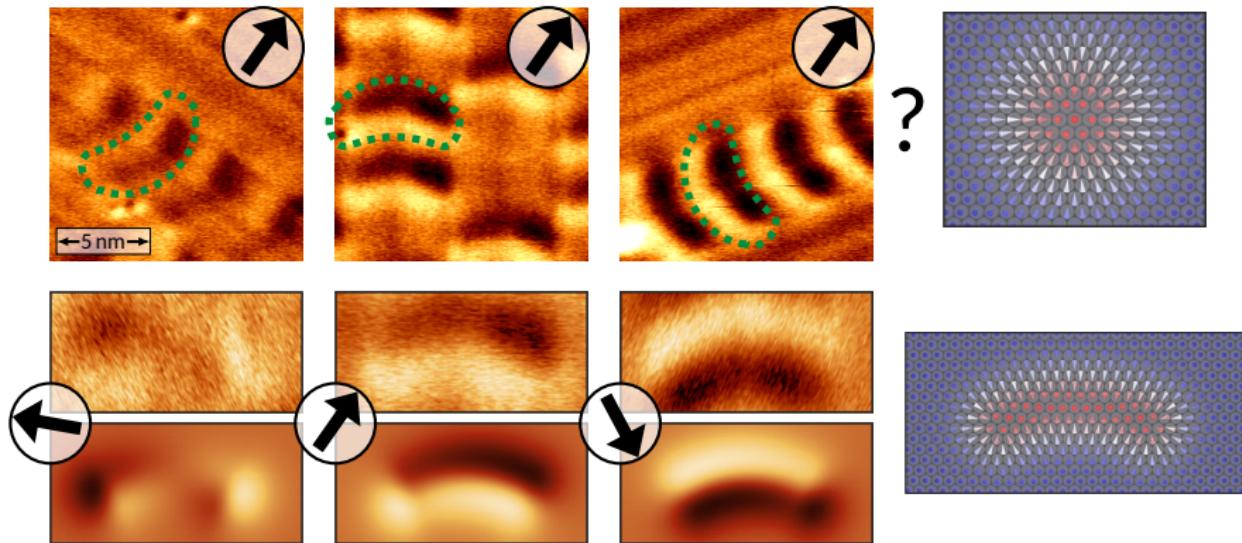
Field dependence of the spirals in the Fe triple layer



Banana shaped skyrmions



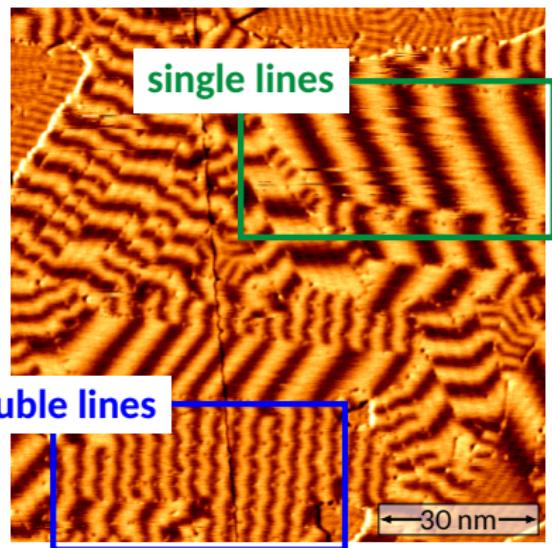
Banana shaped skyrmions



- ▶ In-plane sensitive measurements allow to determine the full 3D spin structure
- ▶ Same topology as the round skyrmions, but distorted by the surface structure

Coexistence of double and single lines

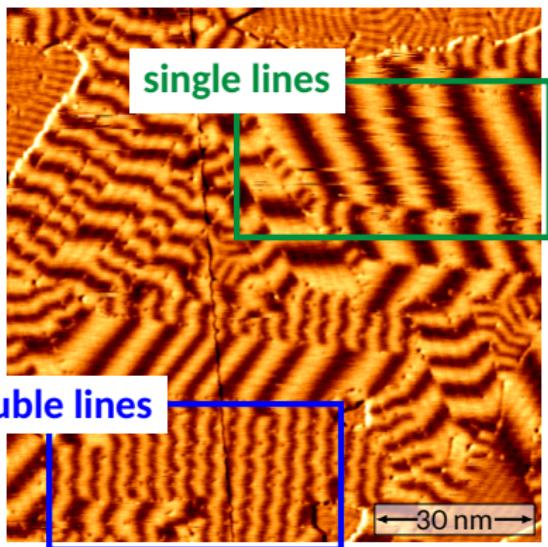
Differential conductance map



-700 mV, 1 nA, Cr bulk tip, 8 K, 0 T

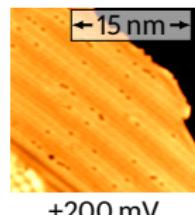
Coexistence of double and single lines

Differential conductance map



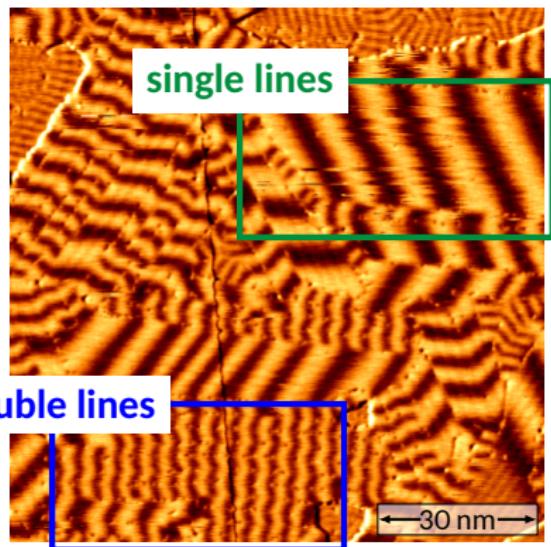
-700 mV, 1 nA, Cr bulk tip, 8 K, 0 T

- ▶ Double line feature only at positive bias
- ▶ Line spacing: 2.2 to 2.8 nm
- ▶ Spin spiral period: 3 to 4 nm
- ▶ Zigzag spiral wavefront



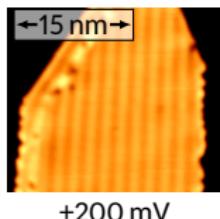
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Differential conductance map



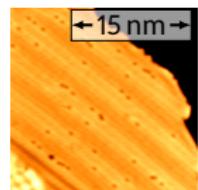
-700 mV, 1 nA, Cr bulk tip, 8 K, 0 T

- ▶ Same appearance at any bias, positive or negative
- ▶ Line spacing:
1.8 to 2.2 nm
- ▶ Spin spiral period:
5 to 10 nm
- ▶ Straight but canted spiral wavefront



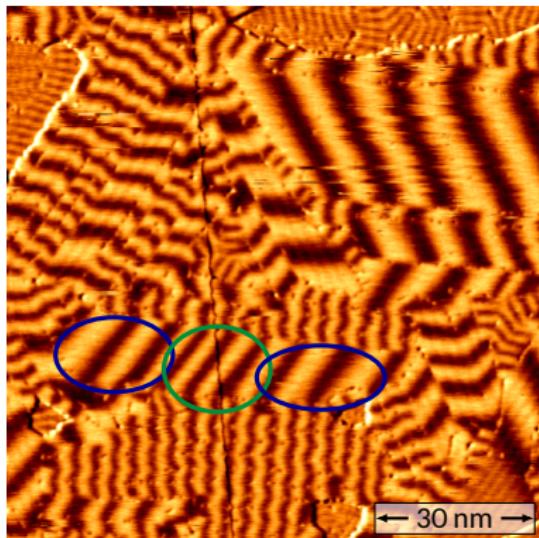
+200 mV

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+200 mV

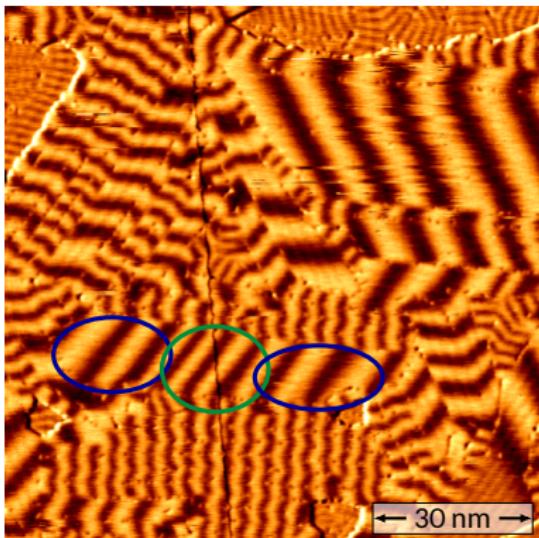
Varying spin spiral period



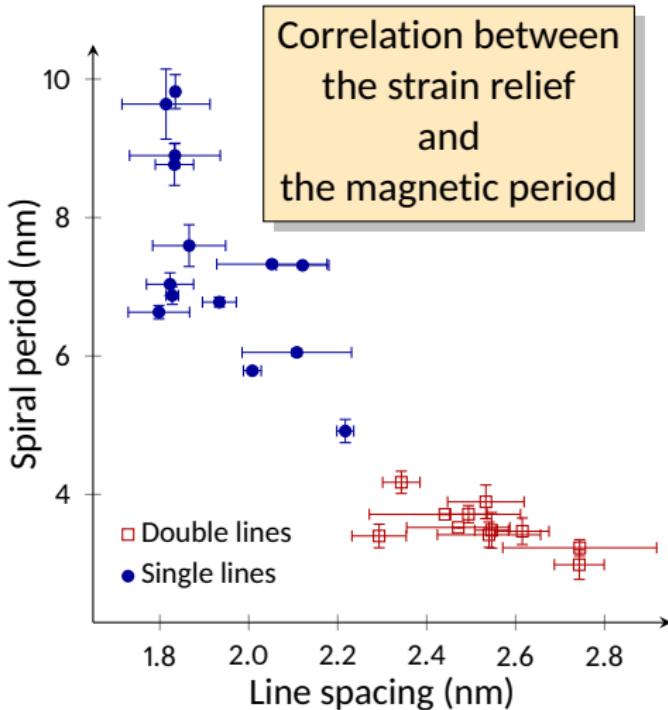
Dislocation lines spacing:



Varying spin spiral period

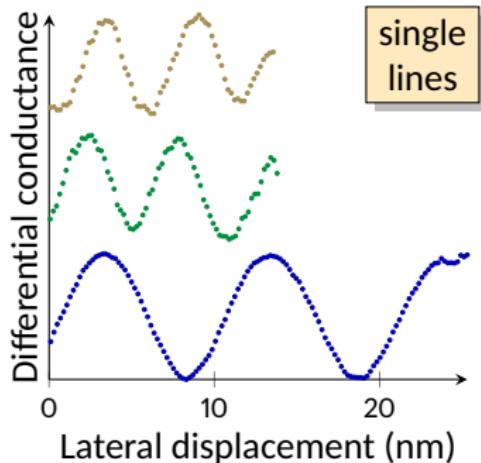
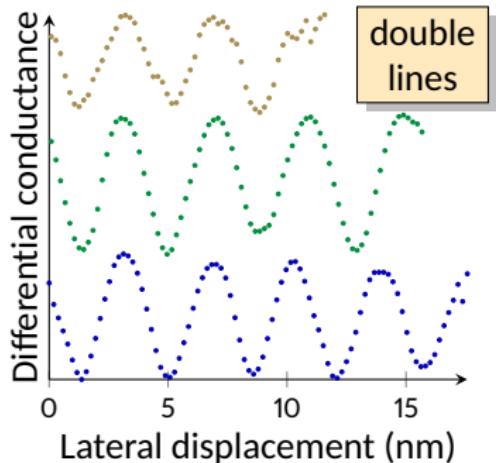


Dislocation lines spacing:



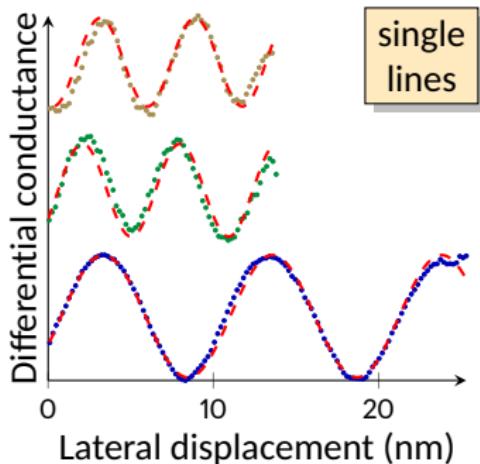
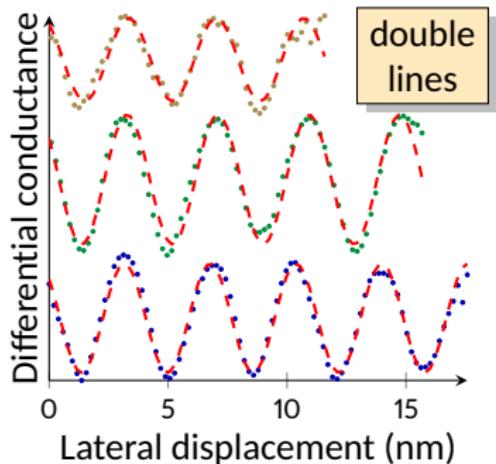
Effective magnetic anisotropy

- Line profiles from several spirals with various periods



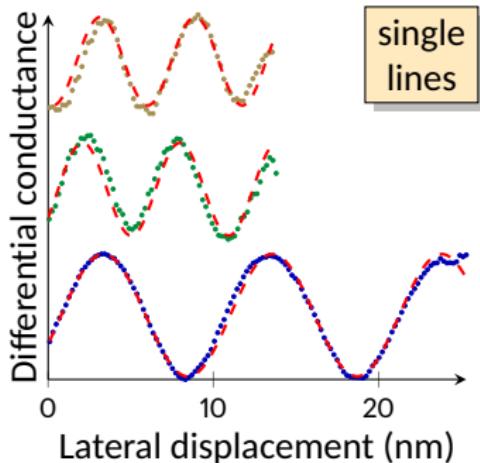
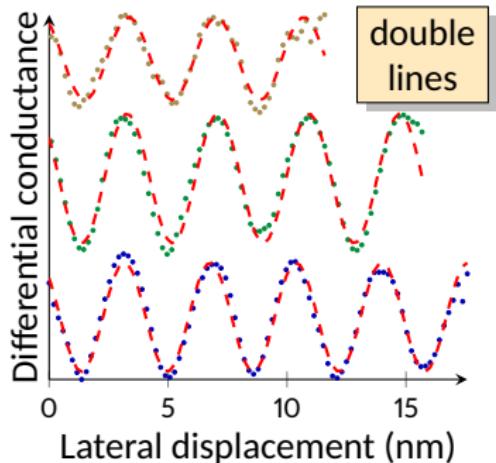
Effective magnetic anisotropy

- ▶ Line profiles from several spirals with various periods
- ▶ Fitting a sine function



Effective magnetic anisotropy

- ▶ Line profiles from several spirals with various periods
- ▶ Fitting a sine function



- ▶ Homogeneous spin spirals \Rightarrow very small anisotropy!

Simple magnetic model

1D model:
$$E = A \sum_i \left(\frac{\partial \mathbf{m}}{\partial x_i} \right)^2 + D \left(m_z \frac{\partial m_x}{\partial x} - m_x \frac{\partial m_z}{\partial x} \right) - K_{\text{eff}} m_z^2$$

- We assume that D is not affected by the strain variations
- We take $K_{\text{eff}} = 0$

⇒ Spin spiral period:
$$\lambda = 4\pi \frac{A}{|D|}$$

$$D = 2.8 \text{ mJ m}^{-2}$$

(Fe/Ir interface)

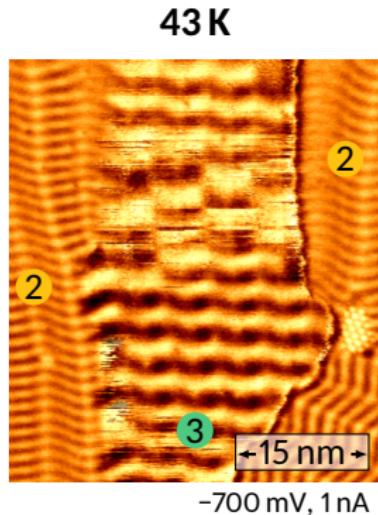
$$3 \text{ nm} \leq \lambda \leq 10 \text{ nm}$$

$$0.6 \text{ pJ m}^{-1} \leq A \leq 2.2 \text{ pJ m}^{-1}$$

A. Bogdanov *et al.* Thermodynamically stable magnetic vortex states in magnetic crystals. *Journal of Magnetism and Magnetic Mat.* 138.3 (1994), 255–269.

Improved thermal stability

- The nanoskyrmion lattice in the monolayer disappears at 28 K

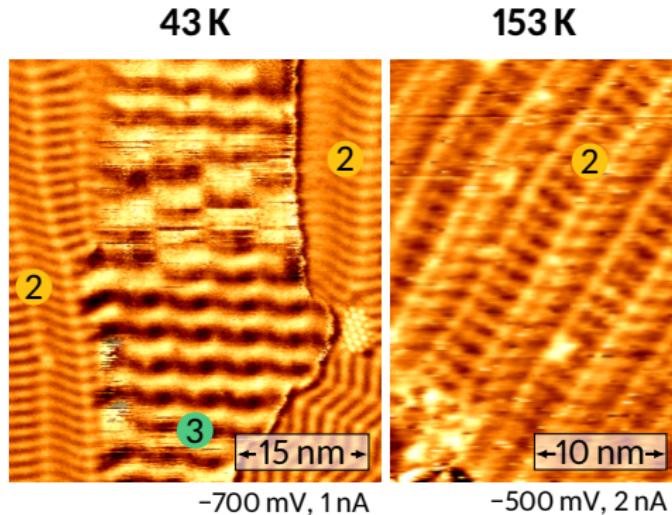


A. Sonntag *et al.* Thermal Stability of an Interface-Stabilized Skyrmion Lattice. *Phys. Rev. Lett.* 113 (2014).

A. Finco *et al.* Temperature-Induced Increase of Spin Spiral Periods. *Physical Review Letters* 119.3 (2017), 037202.

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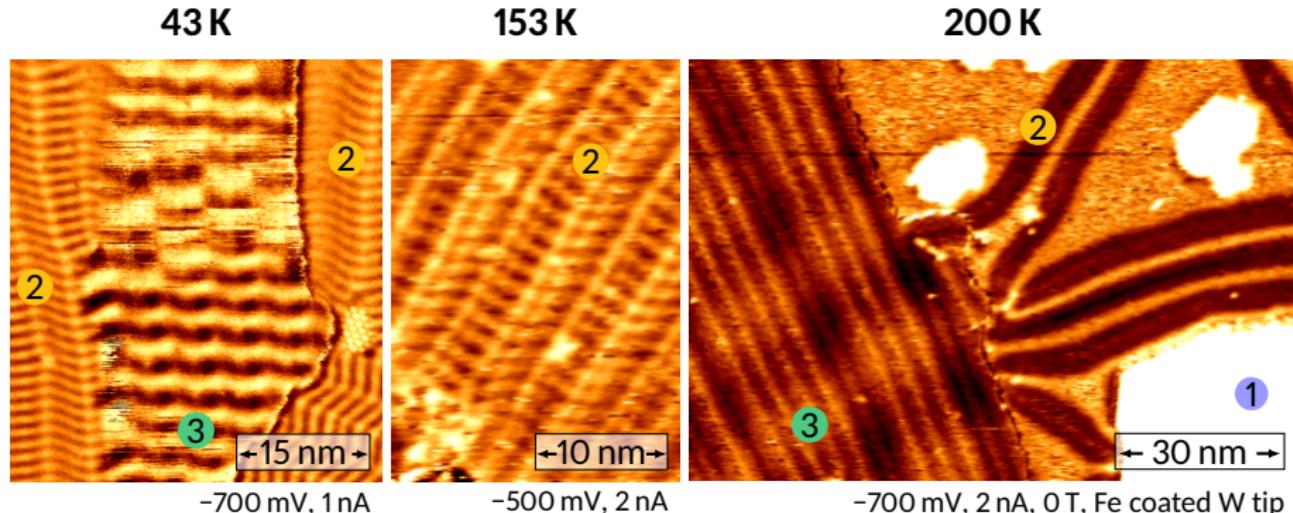


A. Sonntag *et al.* Thermal Stability of an Interface-Stabilized Skyrmion Lattice. *Phys. Rev. Lett.* 113 (2014).

A. Finco *et al.* Temperature-Induced Increase of Spin Spiral Periods. *Physical Review Letters* 119.3 (2017), 037202.

Improved thermal stability

- The nanoskyrmion lattice in the monolayer disappears at 28 K
- The spin spirals in the double layer disappear below 200 K

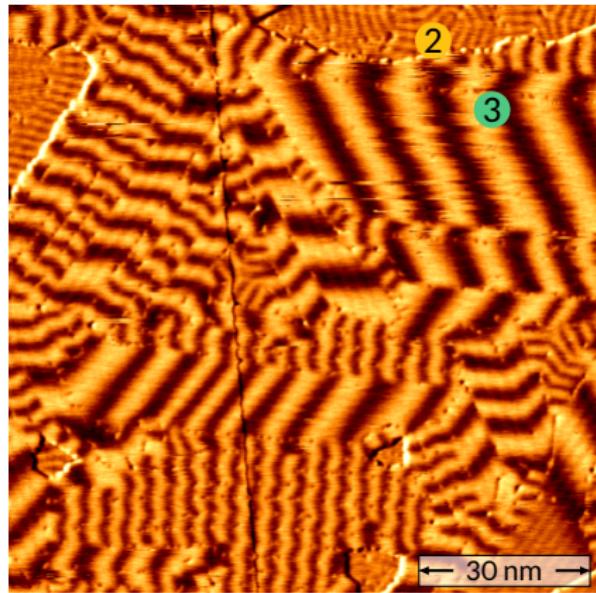


A. Sonntag *et al.* Thermal Stability of an Interface-Stabilized Skyrmion Lattice. *Phys. Rev. Lett.* 113 (2014).

A. Finco *et al.* Temperature-Induced Increase of Spin Spiral Periods. *Physical Review Letters* 119.3 (2017), 037202.

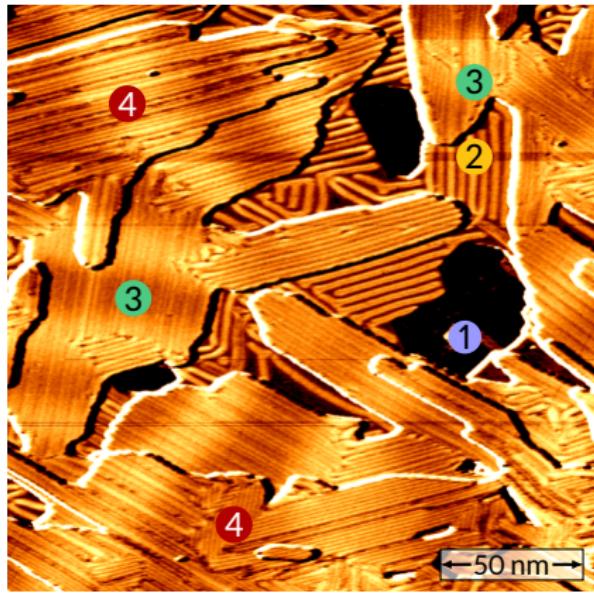
Room temperature spin spirals in the triple layer

8 K



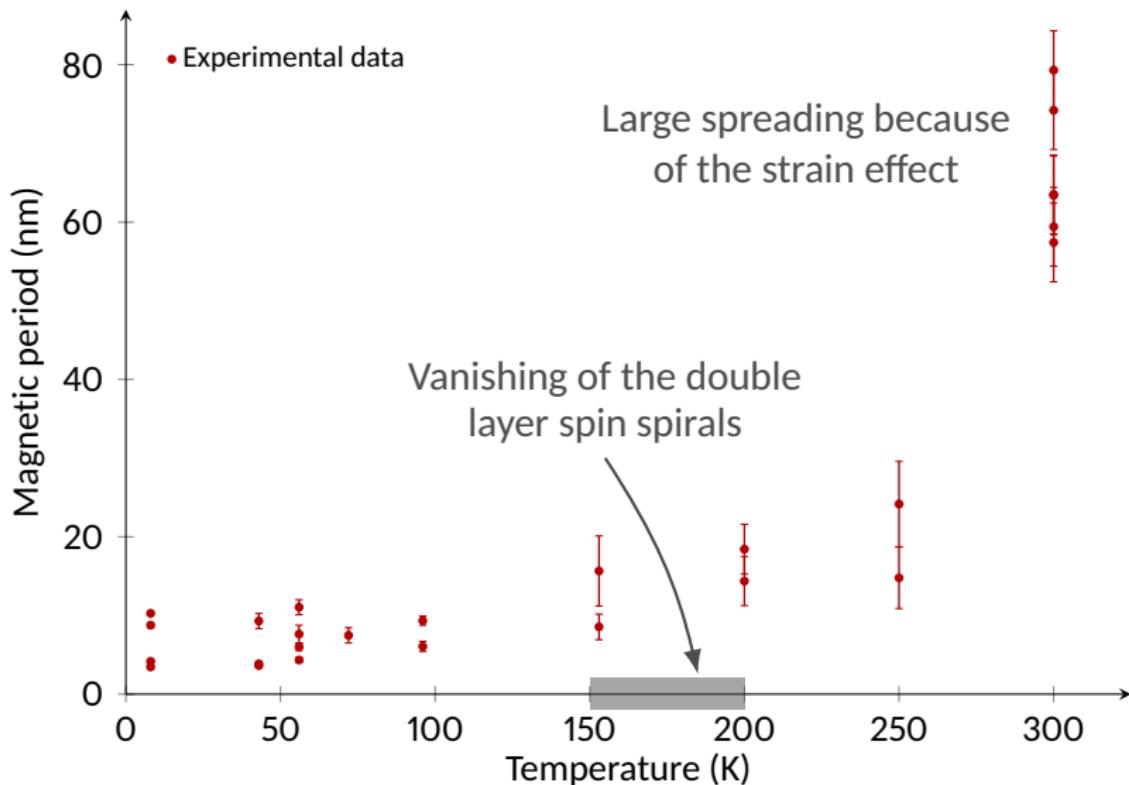
-700 mV, 1 nA, 0 T, Cr bulk tip

300 K



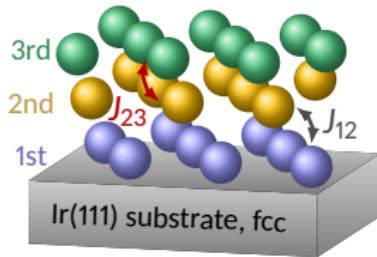
-500 mV, 3 nA, 0 T, Cr bulk tip

Increased spin spiral period



Classical model: different layers

proposed by Levente Rózsa



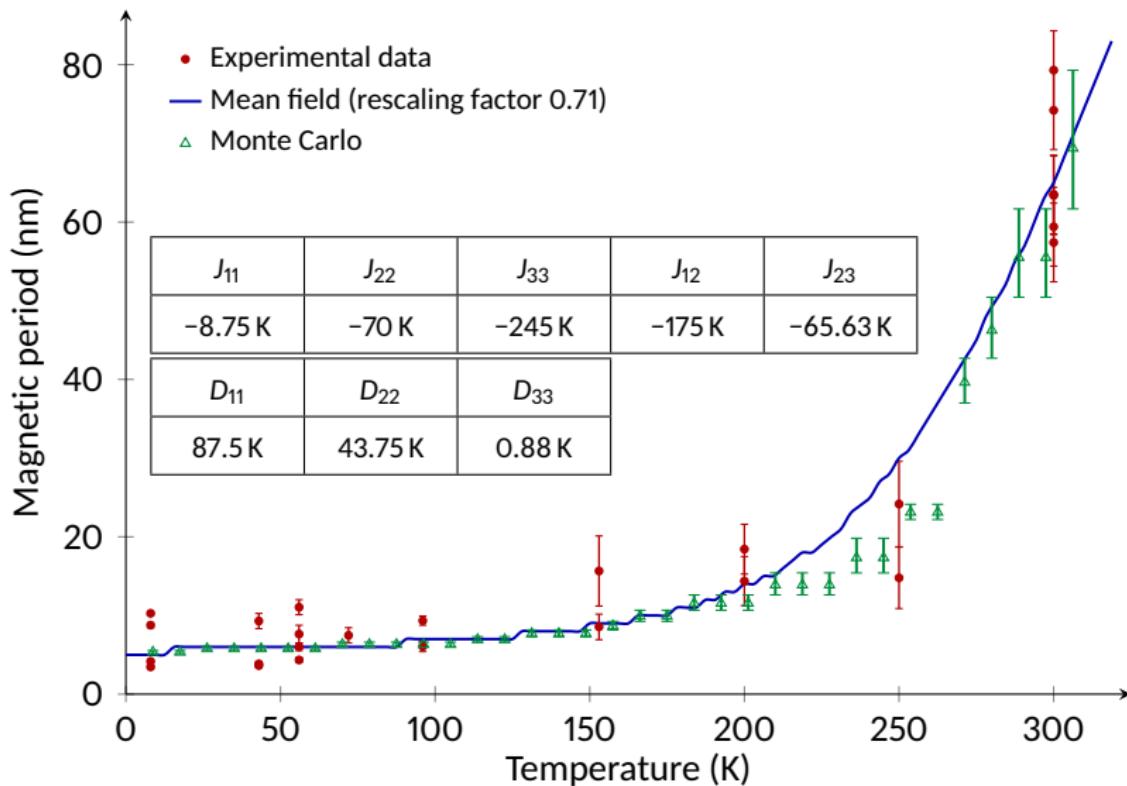
- We assume again $K_{\text{eff}} = 0$
- Different parameters in the 3 layers
- Interlayer exchange couplings

Hamiltonian:

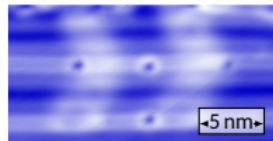
$$H = \frac{1}{2} \sum_{p,q,\langle i,j \rangle} J_{pq,ij} \mathbf{S}_{p,i} \mathbf{S}_{q,j} + \frac{1}{2} \sum_{p,\langle i,j \rangle} D_{pp,ij} (\mathbf{S}_{p,i} \times \mathbf{S}_{p,j})$$

- The mean field order parameter $\langle S_p(k) \rangle$ **decreases faster with temperature** in the 1st and 2nd layers than in the 3rd one.
- This **shifts the free energy minimum towards larger periods**
- Parameters chosen to reproduce the data

Comparison to the experiment



Skyrmion switching with non-magnetic tips!

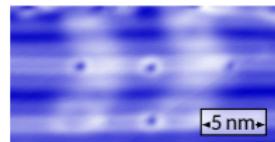


200 mV, 1 nA, 8 K, -1.85 T, W tip

P.-J. Hsu *et al.* Electric-field-driven switching of individual magnetic skyrmions. *Nature Nano* 12 (2017), 123–126.

C. Hanneken *et al.* Electrical detection of magnetic skyrmions by tunnelling non-collinear magnetoresistance. *Nature Nano*. 10 (2015), 1039–1042.

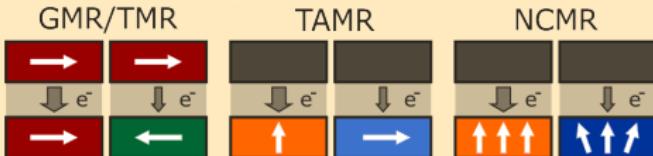
Skyrmion switching with non-magnetic tips!



200 mV, 1 nA, 8 K, -1.85 T, W tip

Imaging mechanism:

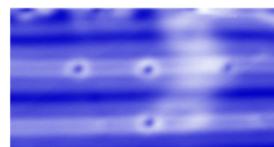
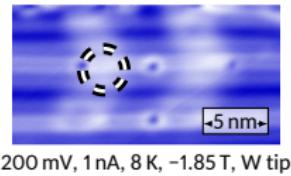
Non-Collinear MagnetoResistance



P.-J. Hsu *et al.* Electric-field-driven switching of individual magnetic skyrmions. *Nature Nano* 12 (2017), 123–126.

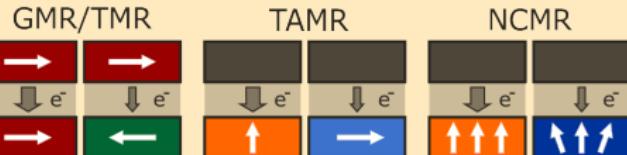
C. Hanneken *et al.* Electrical detection of magnetic skyrmions by tunnelling non-collinear magnetoresistance. *Nature Nano*. 10 (2015), 1039–1042.

Skyrmion switching with non-magnetic tips!



Imaging mechanism:

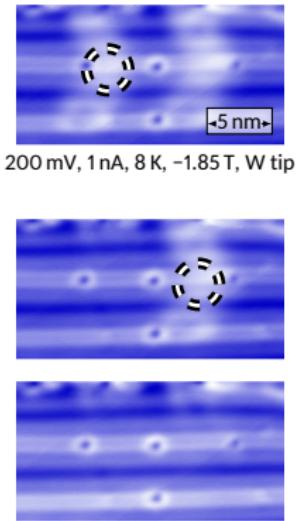
Non-Collinear MagnetoResistance



P.-J. Hsu *et al.* Electric-field-driven switching of individual magnetic skyrmions. *Nature Nano* 12 (2017), 123–126.

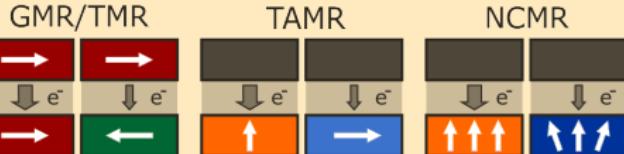
C. Hanneken *et al.* Electrical detection of magnetic skyrmions by tunnelling non-collinear magnetoresistance. *Nature Nano*. 10 (2015), 1039–1042.

Skyrmion switching with non-magnetic tips!



Imaging mechanism:

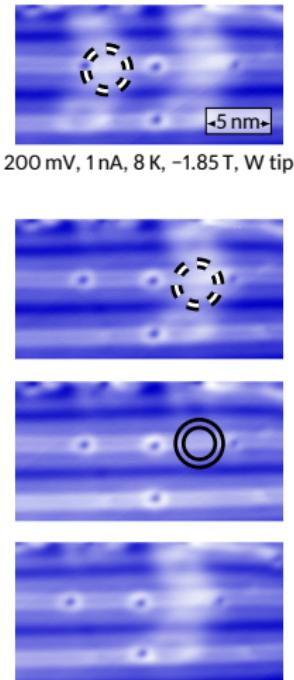
Non-Collinear MagnetoResistance



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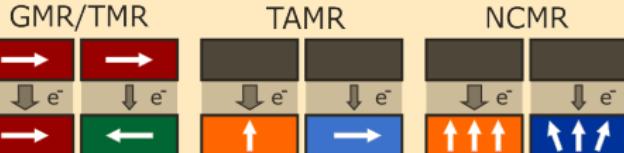
C. Hanneken *et al.* Electrical detection of magnetic skyrmions by tunnelling non-collinear magnetoresistance. *Nature Nano*. 10 (2015), 1039–1042.

Skyrmion switching with non-magnetic tips!



Imaging mechanism:

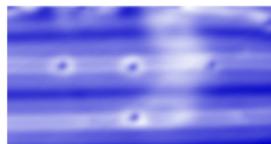
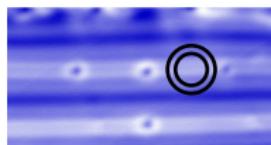
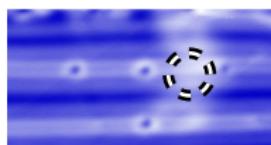
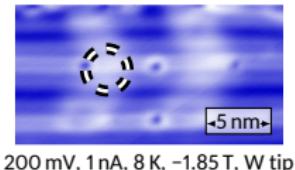
Non-Collinear MagnetoResistance



P.-J. Hsu *et al.* Electric-field-driven switching of individual magnetic skyrmions. *Nature Nano* 12 (2017), 123–126.

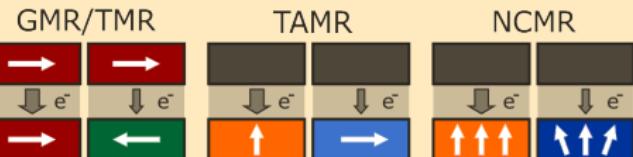
C. Hanneken *et al.* Electrical detection of magnetic skyrmions by tunnelling non-collinear magnetoresistance. *Nature Nano*. 10 (2015), 1039–1042.

Skrymion switching with non-magnetic tips!

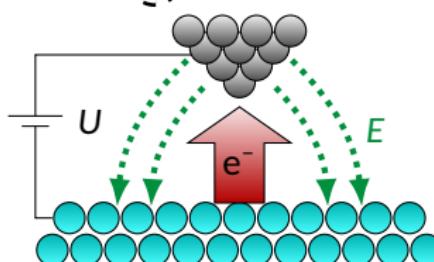


Imaging mechanism:

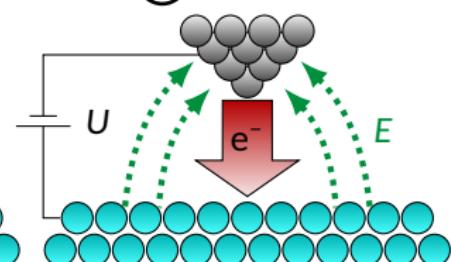
Non-Collinear MagnetoResistance



-4 V deleting



+4 V writing



P.-J. Hsu *et al.* Electric-field-driven switching of individual magnetic skyrmions. *Nature Nano* 12 (2017), 123–126.

C. Hanneken *et al.* Electrical detection of magnetic skyrmions by tunnelling non-collinear magnetoresistance. *Nature Nano*. 10 (2015), 1039–1042.

Electric field driven switching

- ▶ Spin-polarized tip **not** needed
- ▶ Opposite polarity for writing and deleting

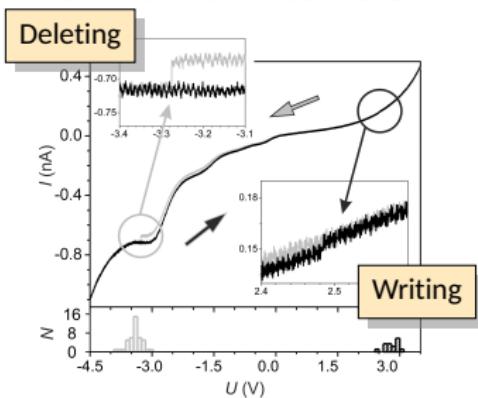
Electric field driven switching

- ▶ Spin-polarized tip **not** needed
- ▶ Opposite polarity for writing and deleting
- ▶ Parallel plates model: $E = -U/d$
 - Measure the switching voltage U for different tip/sample distances d

Electric field driven switching

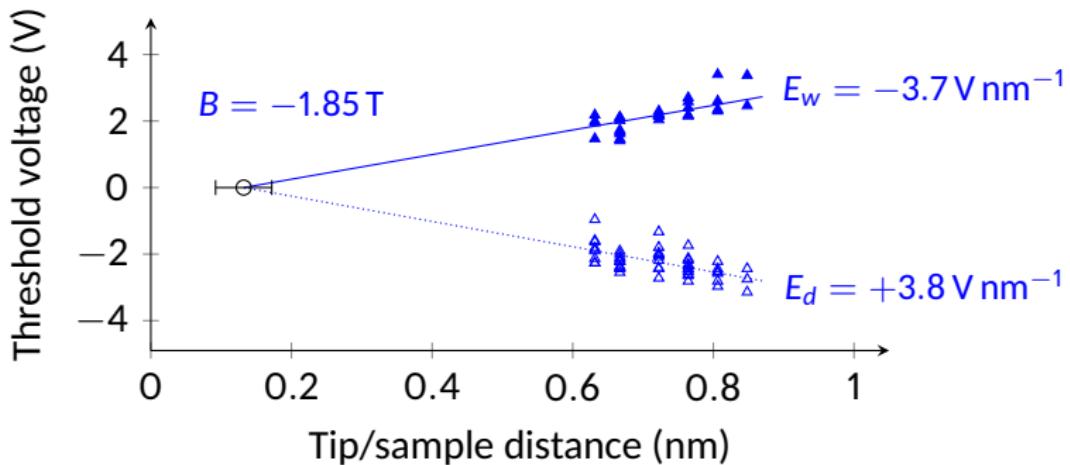
- ▶ Spin-polarized tip **not** needed
- ▶ Opposite polarity for writing and deleting
- ▶ Parallel plates model: $E = -U/d$
 - Measure the switching voltage U for different tip/sample distances d

How do we measure U ?

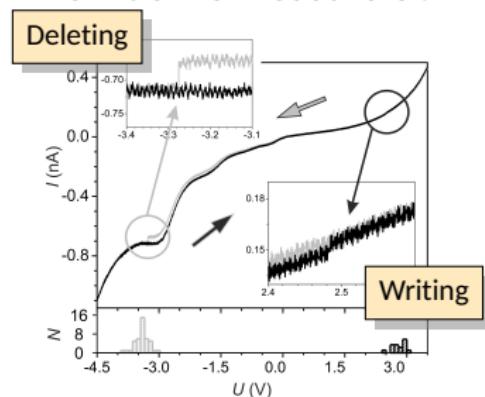


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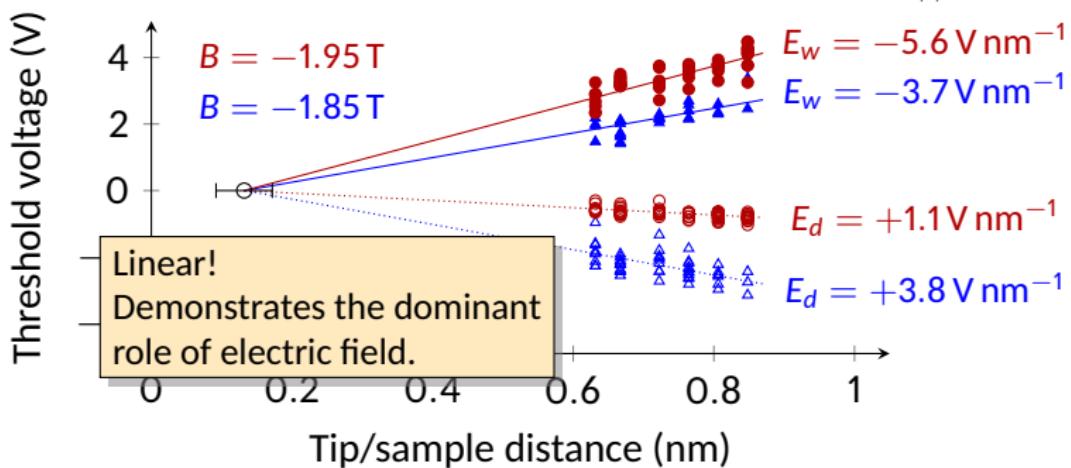


How do we measure U ?

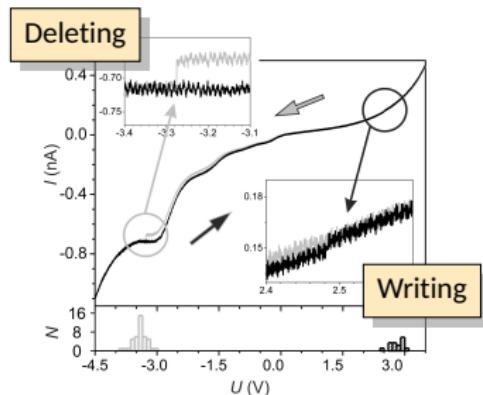


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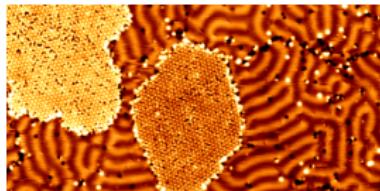


How do we measure U ?

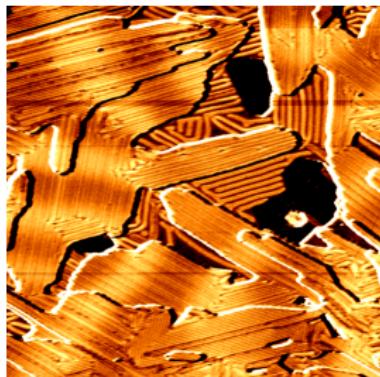


Summary

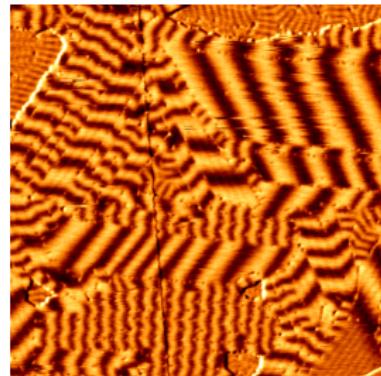
H incorporation



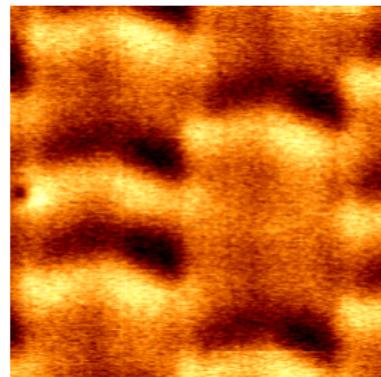
Temperature



Epitaxial strain



Electric field



Acknowledgements

Pin-Jui Hsu

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Thomas Eelbo

André Kubetzka

Kirsten von Bergmann

Levente Rózsa

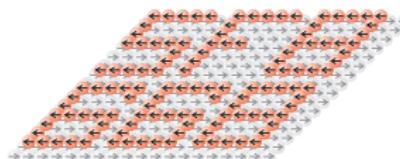
Elena Vedmedenko

Roland Wiesendanger

Krisztián Palotás

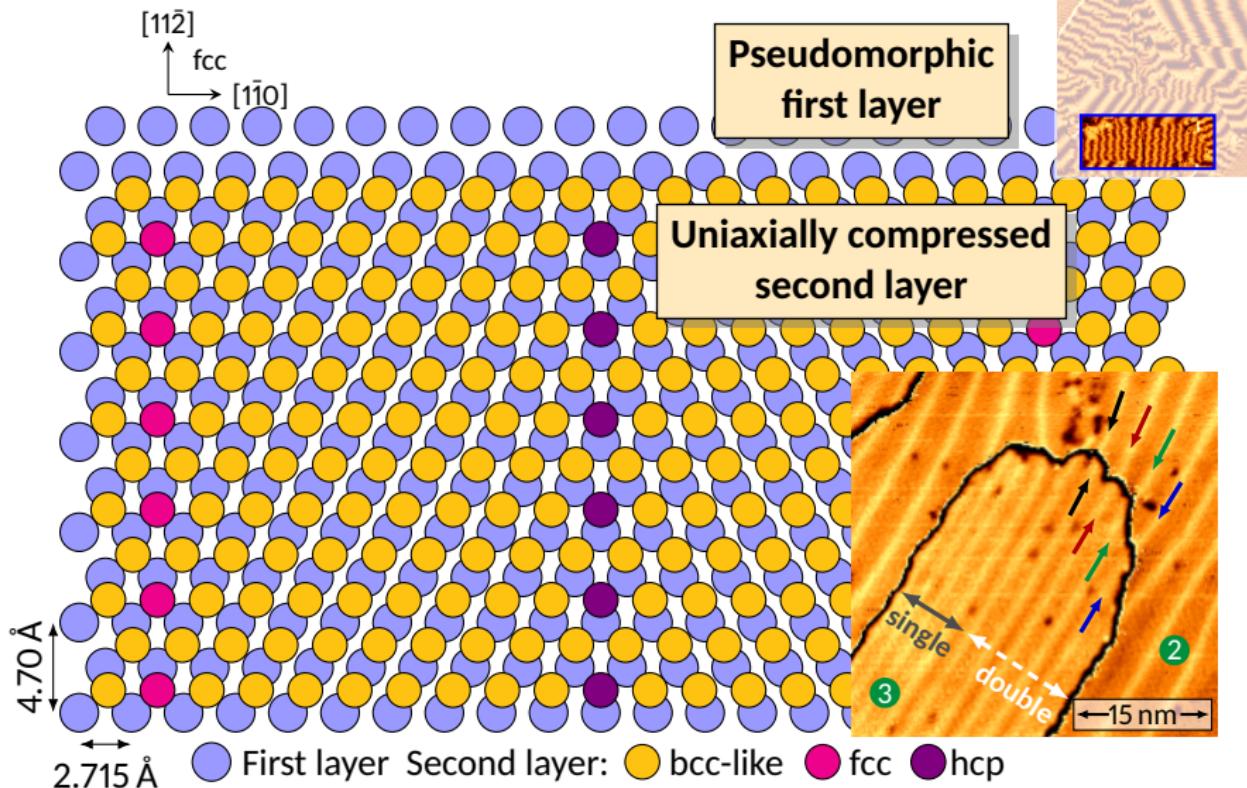
László Udvardi

László Szunyogh

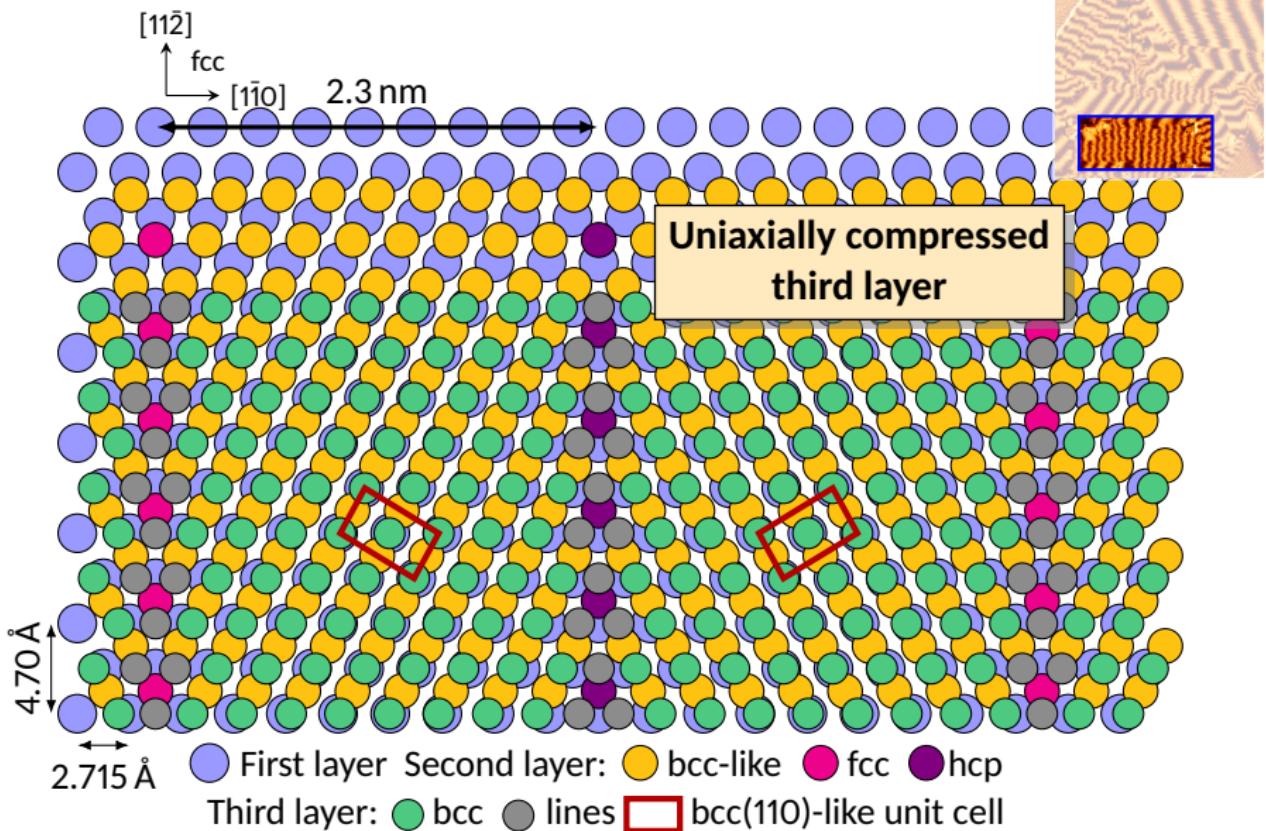


Funded by the Horizon2020
Framework Programme of
the European Union

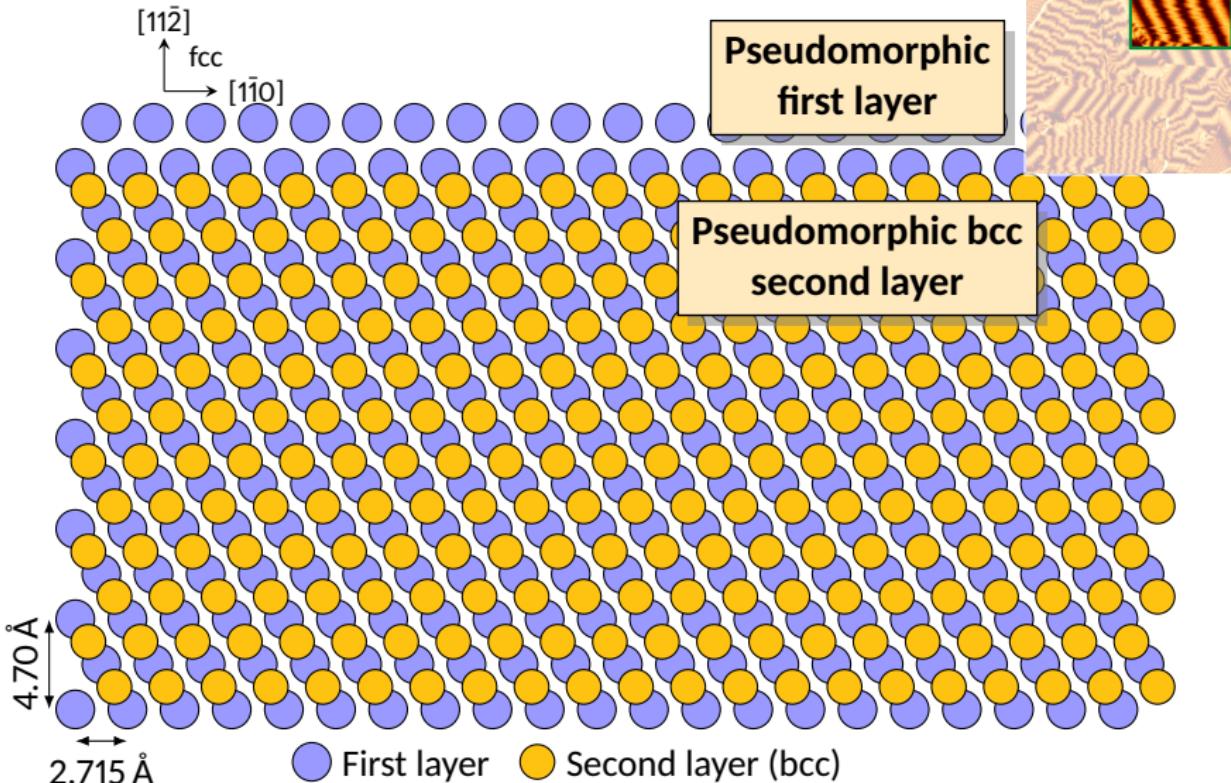
Double lines, atomic structure model



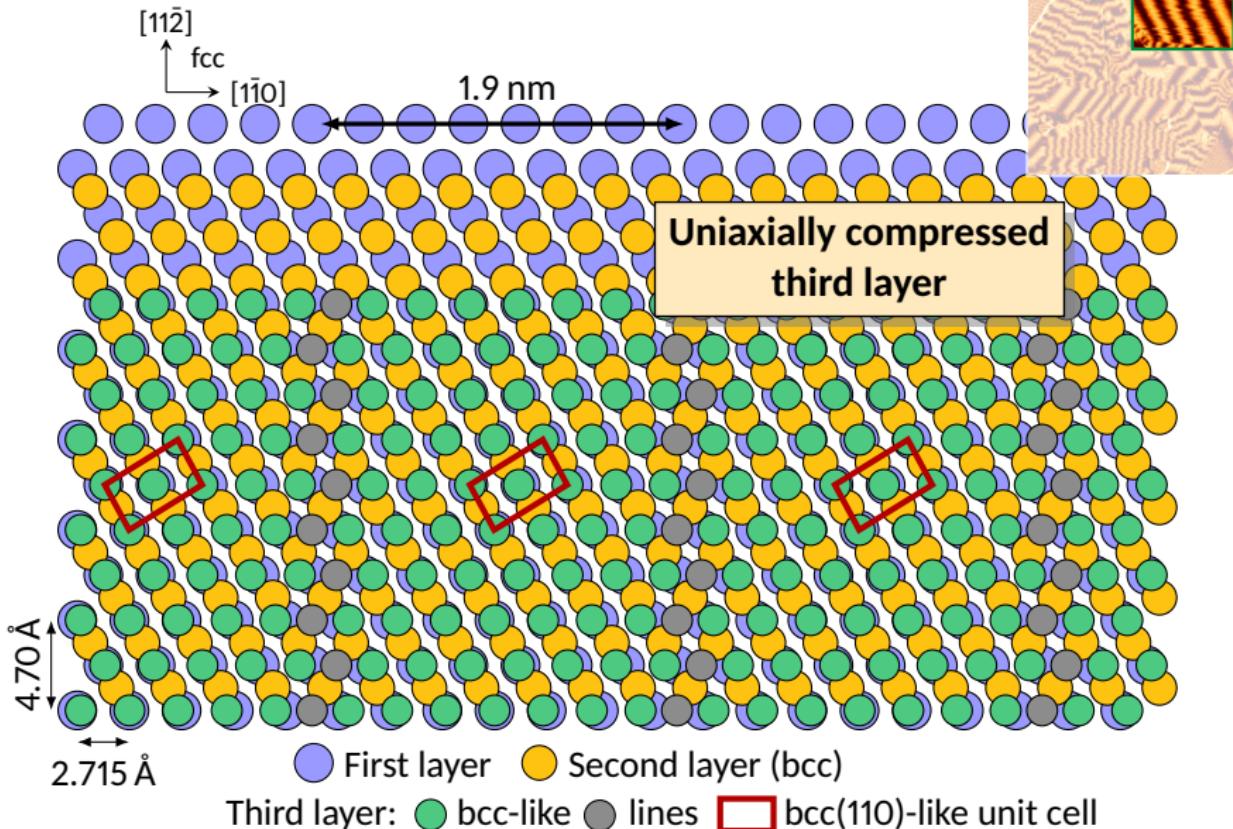
Double lines, atomic structure model



Single lines, atomic structure model

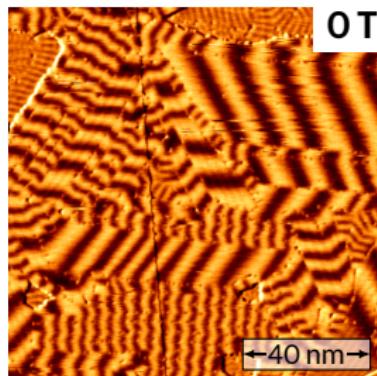


Single lines, atomic structure model

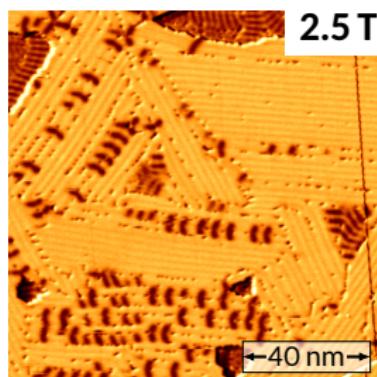
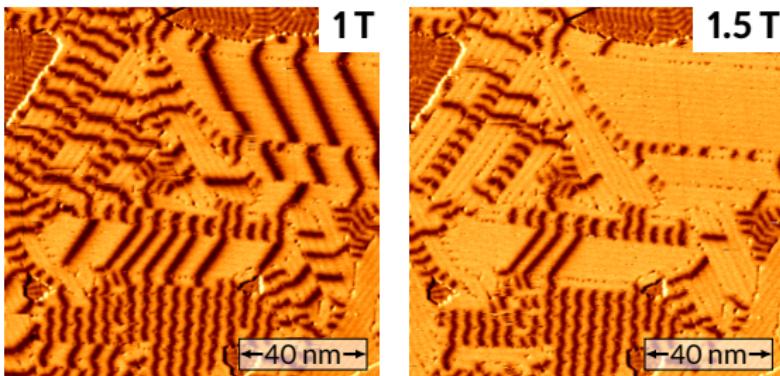
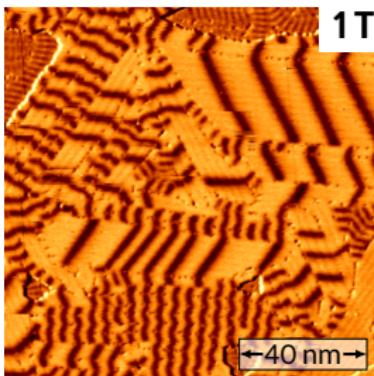


Magnetic phase transition

Differential conductance maps, out-of-plane sensitive tip

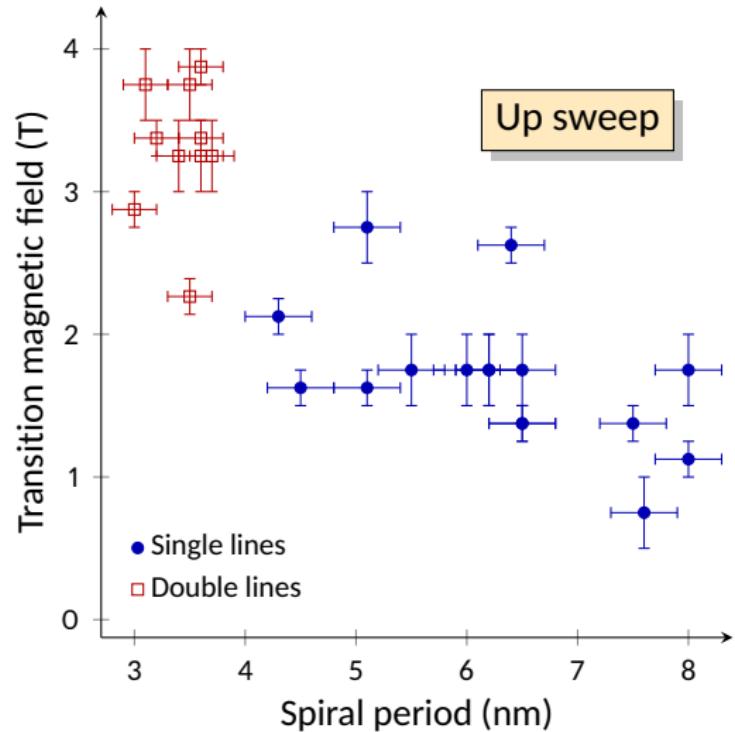


-700 mV, 1 nA, 8 K, Cr bulk tip



- ▶ Spirals in single lines areas become **360° domain walls**
- ▶ Spirals in double lines areas become **skyrmions**
- ▶ Different transition field in every area
 - Variation of the strain relief
 - Pinning on defects
 - Interaction between the adjacent areas

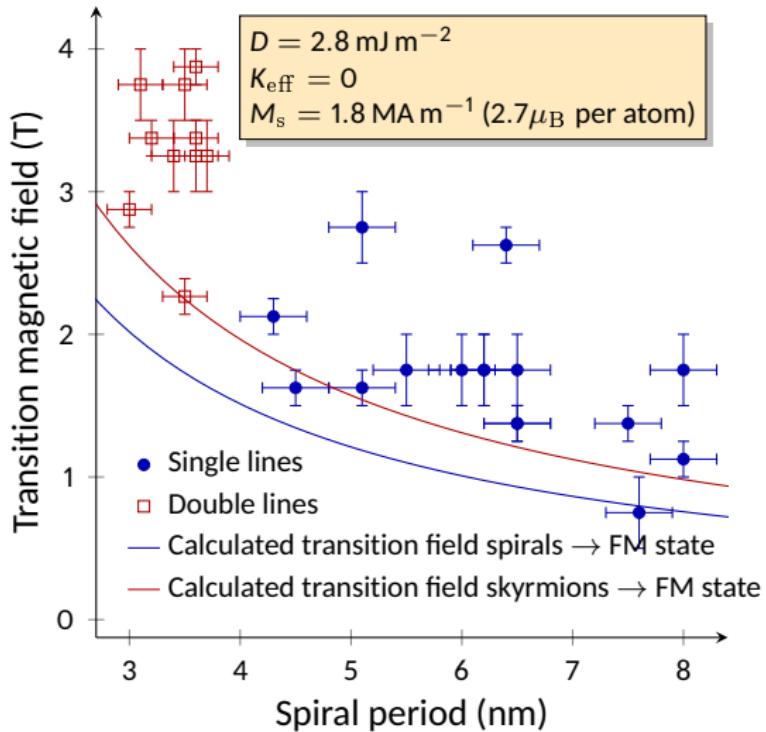
Effect of the dislocation line spacing on the transition field



A. Bogdanov et al. Thermodynamically stable magnetic vortex states in magnetic crystals. *Journal of Magnetism and Magnetic Mat.* 138.3 (1994), 255–269.

A. Finco *et al.* Tailoring noncollinear magnetism by misfit dislocation lines. *Physical Review B* 94.21 (2016), 214402.

Effect of the dislocation line spacing on the transition field



Back to the model, with a Zeeman term:

$$\begin{aligned}\mathcal{E} = & A \sum_i \left(\frac{\partial \mathbf{m}}{\partial x_i} \right)^2 \\ & + D \left(m_z \frac{\partial m_x}{\partial x} - m_x \frac{\partial m_z}{\partial x} \right) \\ & - K_{\text{eff}} m_z^2 - M_s B m_z\end{aligned}$$

$$B_t = \frac{D^2 h_t}{AM_s} = 4\pi \frac{D h_t}{\lambda M_s}$$

$$h_t^{\text{spiral}}(K_{\text{eff}} = 0) = 0.308$$

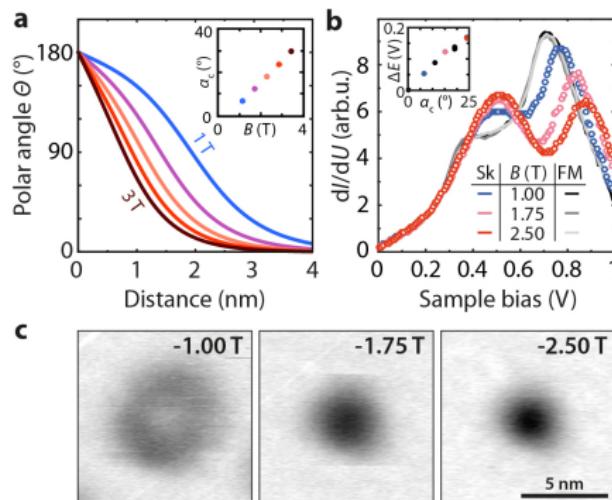
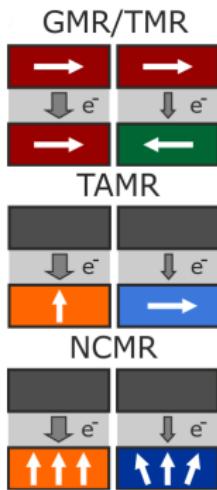
$$h_t^{\text{skyrmion}}(K_{\text{eff}} = 0) = 0.401$$

A. Bogdanov *et al.* Thermodynamically stable magnetic vortex states in magnetic crystals. *Journal of Magnetism and Magnetic Mat.* 138.3 (1994), 255–269.

A. Finco *et al.* Tailoring noncollinear magnetism by misfit dislocation lines. *Physical Review B* 94.21 (2016), 214402.

Noncollinear magnetoresistance (NCMR)

- ▶ Observed first for the skyrmions in PdFe/Ir(111)
- ▶ Non collinearity of the spin texture \Rightarrow different local electronic structure than the FM background
- ▶ Scales with the angle between nearest neighbors magnetic moments



C. Hanneken *et al.* Electrical detection of magnetic skyrmions by tunnelling non-collinear magnetoresistance. *Nature Nano.* 10 (2015), 1039–1042.

Manipulating the skyrmions

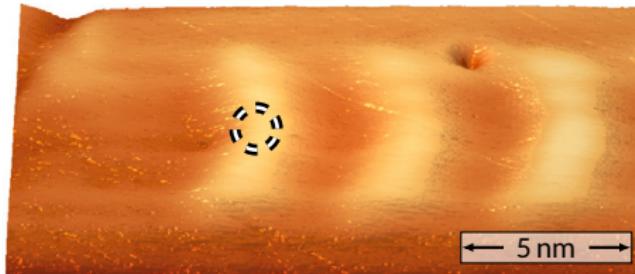
- Reliable skyrmion switching with a Cr bulk tip
- Writing with +3 V ramps
- Deleting with -3 V ramps



Imaging: 300 mV, 0.5 nA, 8 K, 2.5 T

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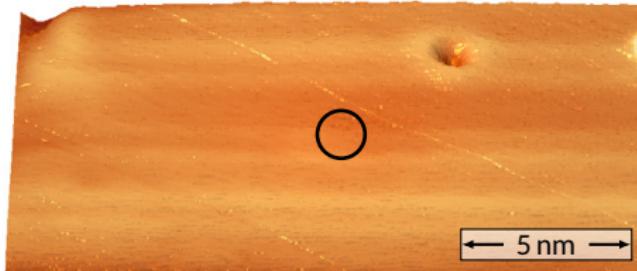
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Switching with a Cr bulk tip

